

Bipolar Transistor

50 V, 15 A, Low V_{CE(sat)}, NPN TO-220F-3SG

2SC6082

Features

- Adoption of MBIT Process
- Low Collector-to-Emitter Saturation Voltage
- Large Current Capacitance
- High-Speed Switching
- This is a Pb-Free Device

Applications

 High-Speed Switching Applications (Switching Regulator, Driver Circuit)

Specifications

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

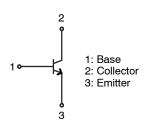
Symbol	Rating	Condition	Value	Unit
V _{CBO}	Collector-to-Base Voltage		60	V
V _{CES}	Collector-to-Emitter Voltage		60	V
V _{CEO}			50	V
V _{EBO}	Emitter-to-Base Voltage		6	V
I _C	Collector Current		15	Α
I _{CP}	Collector Current (Pulse)	PW ≤ 10 μs, duty cycle ≤1%	20	Α
I _B	Base Current		3	Α
P _C	Collector Dissipation		2	W
		T _C = 25°C	23	W
Tj	Junction Temperature		150	°C
Tstg	Storage Temperature		–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

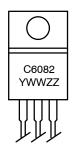


TO-220 Fullpack, 3-Lead / TO-220F-3SG CASE 221AT

ELECTRICAL CONNECTION



MARKING DIAGRAM



C6082

= Device Code

YWW ZZ = Date Code (Year & Week)

= Assembly Lot

ORDERING INFORMATION

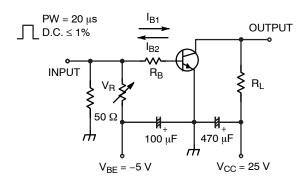
Device	Package	Shipping
2SC6082-1E	TO-220F (Pb-Free)	50 / Tube

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	Collector Cutoff Current	V _{CB} = 40 V, I _E = 0 A	-	-	10	μΑ
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 4 \text{ V}, I_{C} = 0 \text{ A}$	-	-	10	μΑ
H _{FE} 1	DC Current Gain	$V_{CE} = 2 \text{ V, } I_{C} = 330 \text{ mA}$	200	-	560	
H _{FE} 2		V _{CE} = 2 V, I _C = 10 A	50	-	-	
f _T	Gain-Bandwidth Product	V _{CE} = 10 V, I _C = 2 A	-	195	-	MHz
Cob	Output Capacitance	V _{CB} = 10 V, f = 1 MHz	-	85	-	pF
V _{CE} (sat)	Collector-to-Emitter Saturation Voltage	I _C = 7.5 mA, I _B = 375 mA	-	200	400	mV
V _{BE} (sat)	Base-to-Emitter Saturation Voltage	$I_C = 7.5 \text{ mA}, I_B = 375 \text{ mA}$	-	-	1.2	V
V _{(BR)CBO}	Collector-to-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0 A$	60	-	-	V
V _{(BR)CES}	Collector-to-Emitter Breakdown Voltage	I_C = 100 μA, R_{BE} = 0 Ω	60	-	-	V
V _{(BR)CEO}		$I_C = 1$ mA, $R_{BE} = \infty$	50	-	-	V
V _{(BR)EBO}	Emitter-to-Base Breakdown Voltage	I _E = 100 μA, I _C = 0 A	5	-	-	V
t _{on}	Turn-On Time	See specified Test Circuit		52	-	ns
t _{stg}	Storage Time	1		560	-	ns
t _f	Fall Time			37	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

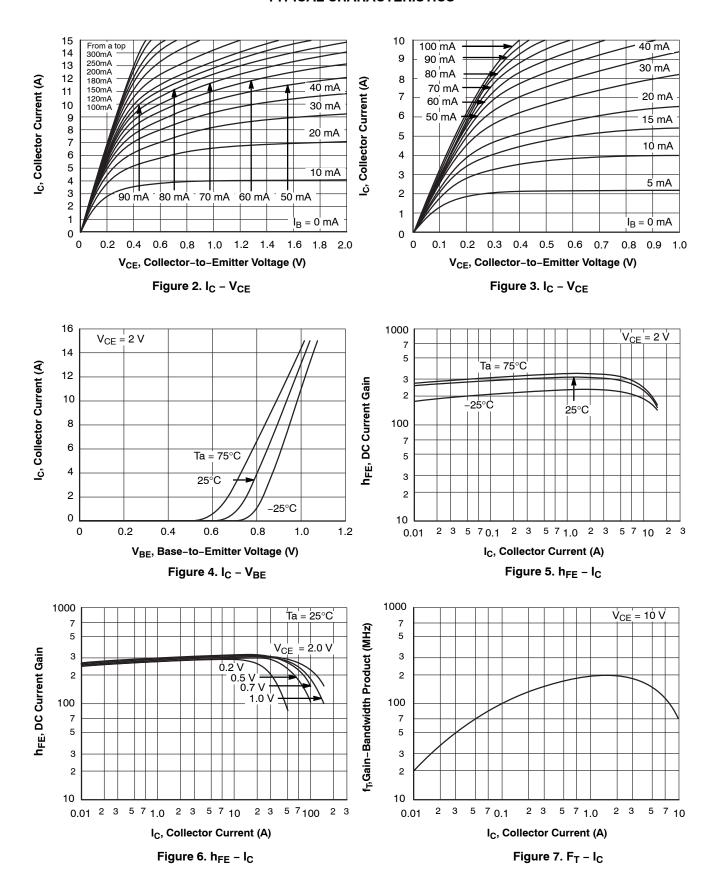
Switching Time Test Circuit



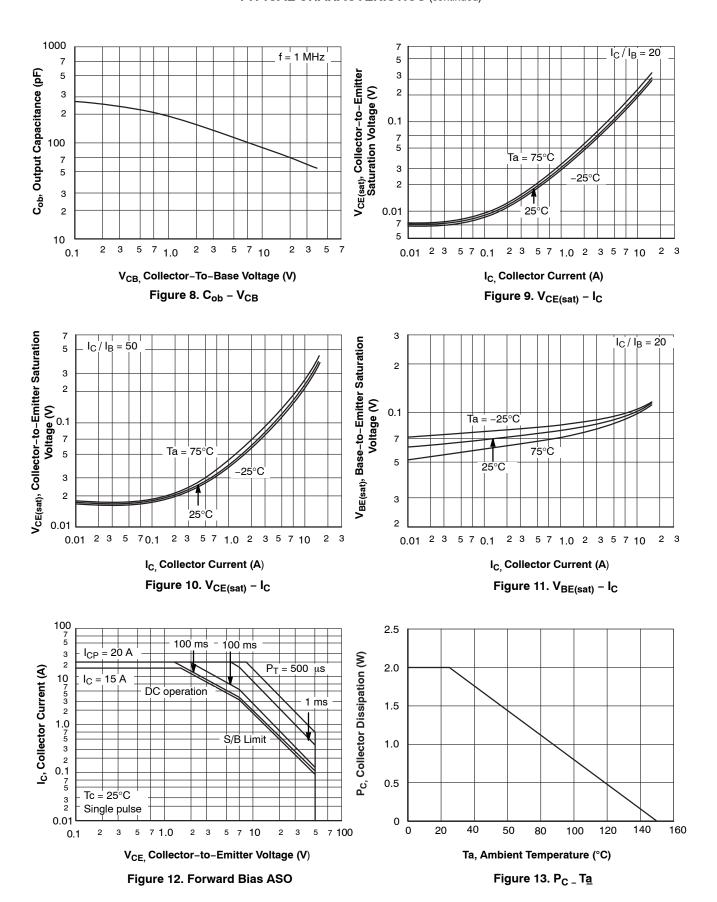
 $I_C = 20I_{B1} = -20I_{B2} = 5 \text{ A}$

Figure 1. Switching Time Test Circuit

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)



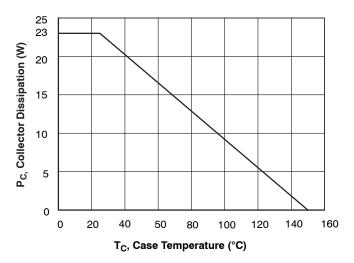
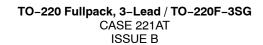
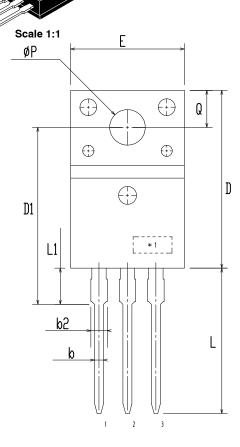


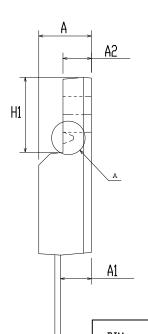
Figure 14. P_C – T_C

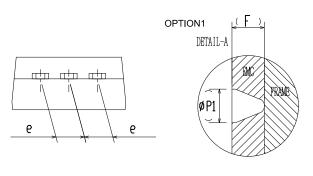




DATE 19 JAN 2021







DIM	HILLIHITIKS			
ויונע	MIN	NDM	MAX	
Α	4.50	4.70	4.90	
A1	2.56	2.76	2.96	
A2	2.34	2.54	2.74	
b	0.70	0.80	0.90	
b2	~	2	1.47	
С	0.45	0.50	0.60	
D	15.67	15.87	16.07	
D1	15.60	15.80	16.00	
E	9.96	10.16	10.36	
е	2.34	2.54	2.74	
F	~	0.84	2	
H1	6.48	6.68	6.88	
L	12.78	12.98	13.18	
L1	3.03	3.23	3.43	
ØΡ	2.98	3.18	3.38	
Ø P1	~	1.00	~	
Q	3.20	3.30	3.40	

MILL IMITERS

NOTES:

- A. DIMENSION AND TOLERANCE AS ASME Y14.5-2009
- B. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUCSIONS.

C

C. OPTION 1 - WITH SUPPORT PIN HOLE OPTION 2 - NO SUPPORT PIN HOLE

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DESCRIPTION:	TO-220 FULLPACK, 3-LEAD / TO-220F-3SG		PAGE 1 OF 1	

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